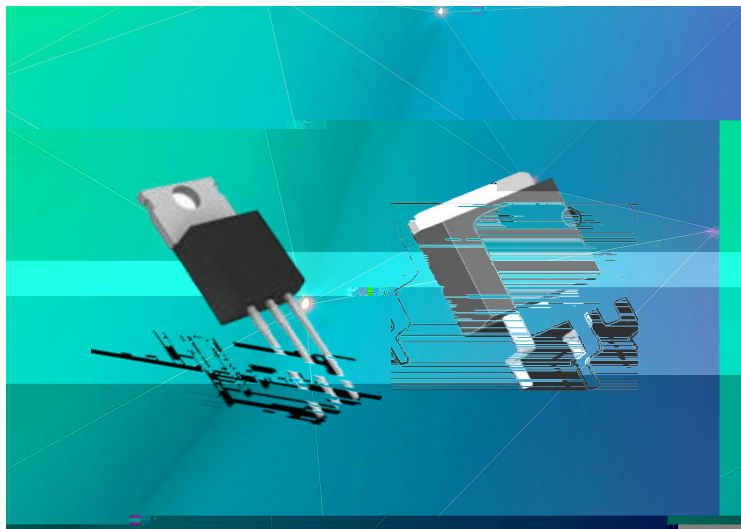


# 微沟



TO-220/TO-263

650V IGBT

1. 650V
3. 50A @  $T_c = 100$
4.  $I_{cm}$  300A



Product Name	$V_{CES}$ (V)	$I_c$ (A)	$V_{GE(th)}$ (V)	$V_{CE(sat)}$ (V)	$V_F$ (V)	$P_d$ (W)	$T_j$
DGP50N 65ATS2A	650V	50A	4.8	1.4	-	283	-40~175
DGB50N 65ATS2A	650V	50A	4.8	1.4	-	283	-40~175



1. Micro-trench process platform, a highly cost-

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New Product Announcement